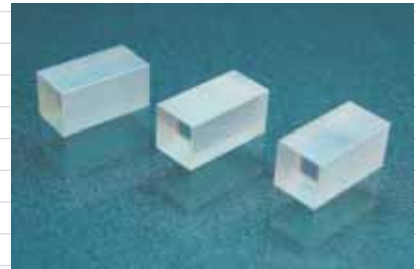


**Nd:GdVO<sub>4</sub>** (Neodymium doped Gadolinium Vanadate) Crystals is an excellent ideal laser host material for the DPSS (Diode pumped Solid State) micro/mini lasers due to its good physical, optical and mechanical properties. It offers higher slope efficiency than Nd:YAG crystal and better thermal conductivity, higher power output than Nd:YVO<sub>4</sub> crystal.

### Specification:

<b>Nd Dopant Level:</b>	0.2-3atm%
<b>Standard Dimension:</b>	3x3mm x 3-12m <sup>3</sup>
<b>Orientation:</b>	α-cut crystalline direction(+/-0.50)
<b>Dimensional Tolerance:</b>	+/-0.1mm(typical)
<b>Wavefront Distortion:</b>	<λ/8@632.8nm
<b>Surface quality:</b>	better than 20/10 Scratch/Dig
<b>Parallelism:</b>	< 10 arc seconds
<b>Perpendicularity:</b>	< 5 arc minutes
<b>Surface Flatness:</b>	<λ/10 at 632.8nm
<b>Clear Aperture:</b>	>Central 95%
<b>Chamfer:</b>	<0.15mmx45deg
<b>Damage Threshold:</b>	>15J/cm <sup>2</sup> (rods without coating) over 700 MW/cm <sup>2</sup> (coating)
<b>Coating:</b>	1.AR@1064nm R<0.1% 2.AR@1064nm R< 0.1% & HT@808nm T>95% 3.HR@1064nm R>99.8% & HR@532nm R>99% & HT@808nm T>95%



### Properties:

Crystal Structure	Zircon Tetragonal, space group D <sub>4h</sub> , a=b=7.21, c=6.35
Melting Point	1780°C
Density	5.47g/cm <sup>3</sup>
Mohs Hardness	Glass-like, ~ 5
Thermal Expansion Coefficient	α <sub>a</sub> =1.5x10 <sup>-6</sup> /K, α <sub>c</sub> =7.3x10 <sup>-6</sup> /K
Thermal Conductivity Coefficient	11.7 W/m/K <110>
Peak Absorption Wavelength	808.5 nm
Lasing Wavelength	912.6 nm, 1063.1 nm, 1341.3 nm
Crystal Class	Positive uniaxial, n <sub>o</sub> =n <sub>a</sub> =n <sub>b</sub> , n <sub>e</sub> =n <sub>c</sub> n <sub>o</sub> =1.9854, n <sub>e</sub> =2.1981, @ 1064nm n <sub>o</sub> =2.038184, n <sub>e</sub> =2.292962, @ 532nm n <sub>o</sub> =1.9977322, n <sub>e</sub> =2.219864, @ 808nm
Thermal Optical Coefficient	dn/dT=4.7x10 <sup>-6</sup> /K
Stimulated Emission Cross-Section	7.60x10 <sup>-19</sup> cm <sup>2</sup> , @1064 nm <sup>2</sup>
Fluorescent Lifetime Nd=1.2 atm%	95 μs (1 atm% Nd doped) @ 808 nm
Loss Coefficient	0.003 cm <sup>-1</sup> @ 1064 nm
Absorption Coefficient Nd=1.2 atm%	74 cm <sup>-1</sup> @ 808 nm (1.2%)
Absorption Length Nd=1.2 atm%	0.18 mm @ 808 nm
Intrinsic Loss Nd=1.2 atm%	Less 0.1% cm <sup>-1</sup> , @1064 nm
Line width	0.6 nm
Polarized Laser Emission	π parallel to optic axis (c-axis)
Diode Pumped Optical to Optical Efficiency	> 60%
Sellmeier Equation (for pure GdVO <sub>4</sub> crystals)	n <sub>o</sub> <sup>2</sup> =4.734369+0.1216149/(λ <sup>2</sup> -0.0523664)-0.013927λ <sup>2</sup> n <sub>e</sub> <sup>2</sup> =3.8987165+0.05990622/(λ <sup>2</sup> -0.0514395)-0.011319λ <sup>2</sup>